

**Features**

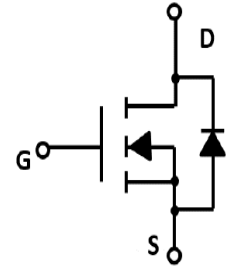
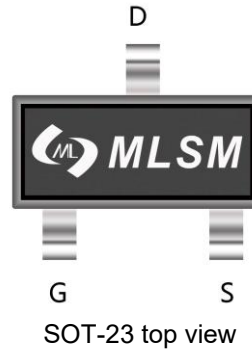
- Trench Power MV MOSFET technology
- Excellent package for heat dissipation
- High density cell design for low  $R_{DS(ON)}$

**Product Summary**

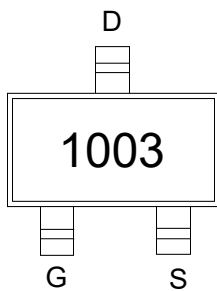
$V_{DS}$	$R_{DS(ON)}$ TYP	$I_D$
100V	190mΩ@10V	3A
	230mΩ@4.5V	

**Application**

- DC-DC Converters
- Power management functions



Schematic diagram



1003: Device code

Marking and pin assignment



Halogen-Free

**Absolute Maximum Ratings (TA=25°C unless otherwise noted)**

Symbol	Parameter	Rating	Unit
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**Common Ratings (TC=25°C Unless Otherwise Noted)**

$V_{DS}$	Drain-Source Breakdown Voltage	100	V
$V_{GS}$	Gate-Source Voltage	±20	V
$T_J$	Maximum Junction Temperature	150	°C
$T_{STG}$	Storage Temperature Range	-50 to 155	°C
$I_S$	Diode Continuous Forward Current	$T_c=25^\circ\text{C}$ 3	A

**Mounted on Large Heat Sink**

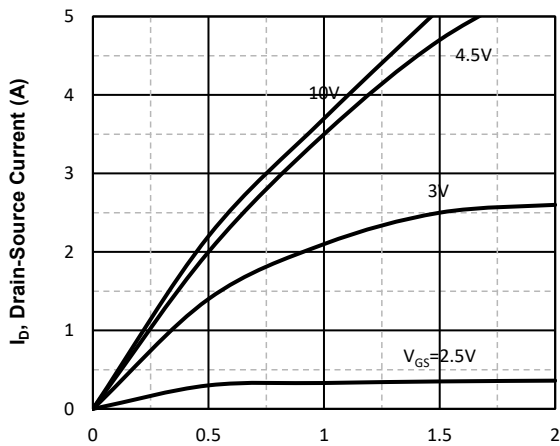
$I_{DM}$	Pulse Drain Current Tested	$T_c=25^\circ\text{C}$ 9	A
$I_D$	Continuous Drain Current	$T_c=25^\circ\text{C}$ 3	A
$P_D$	Maximum Power Dissipation	$T_c=25^\circ\text{C}$ 1.3	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	96	°C/W

**Ordering Information (Example)**

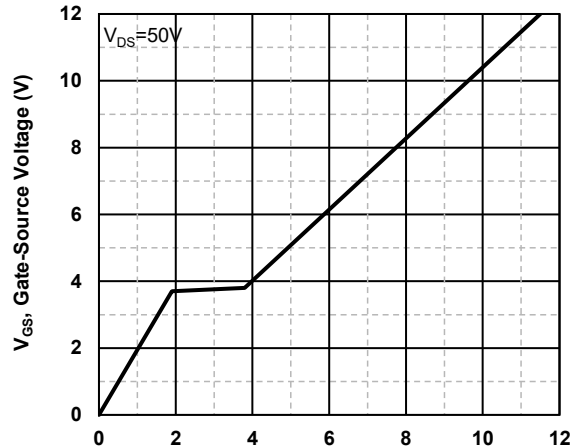
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MLS1003	SOT-23	1003	3,000	45,000	180,000	7"reel

Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T <sub>J</sub> = 25°C (unless otherwise stated)						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	100	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V	--	--	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1.0	1.8	2.5	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =3.0A	--	190	300	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =1.5A	--	230	400	mΩ
Dynamic Electrical Characteristics @ T <sub>J</sub> = 25°C (unless otherwise stated)						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHz	--	387	--	pF
C <sub>OSS</sub>	Output Capacitance		--	30	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	28	--	pF
Switching Characteristics						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =50V, I <sub>D</sub> =3A, V <sub>GS</sub> =10V	--	9.5	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	1.8	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	2	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DS</sub> =50V, I <sub>D</sub> =1.3A, V <sub>GS</sub> =10V, R <sub>G</sub> =1Ω	--	4	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	17.5	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	13	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	28	--	nS
Source- Drain Diode Characteristics						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>S</sub> =3A	--	--	1.2	V

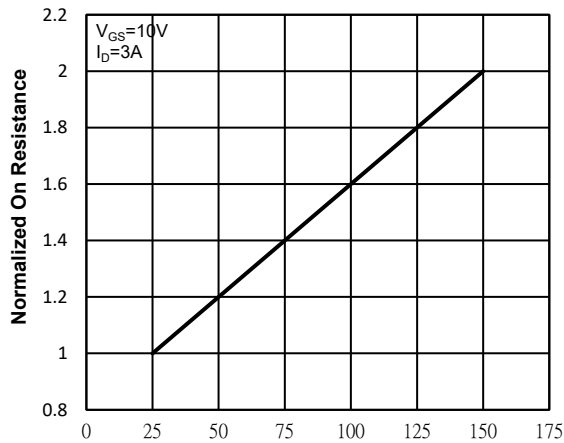
**Typical Operating Characteristics**



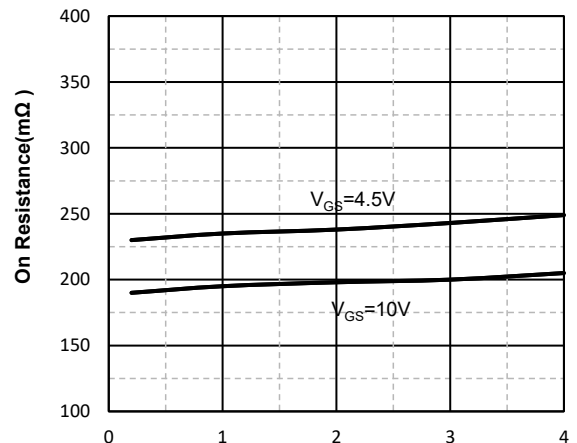
**V<sub>DS</sub>, Drain -Source Voltage (V)**  
**Fig1. Typical Output Characteristics**



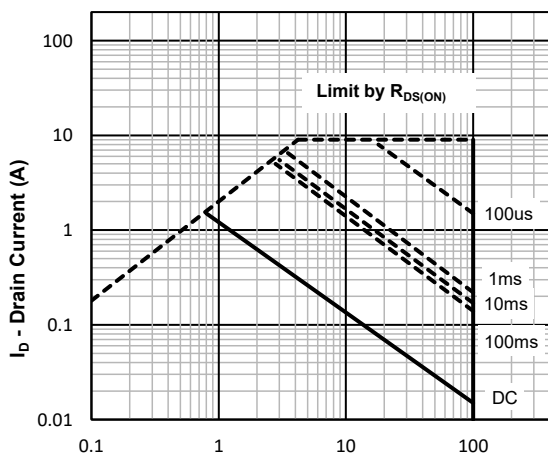
**Qg -Total Gate Charge (nC)**  
**Fig2. Typical Gate Charge Vs. Gate-Source Voltage**



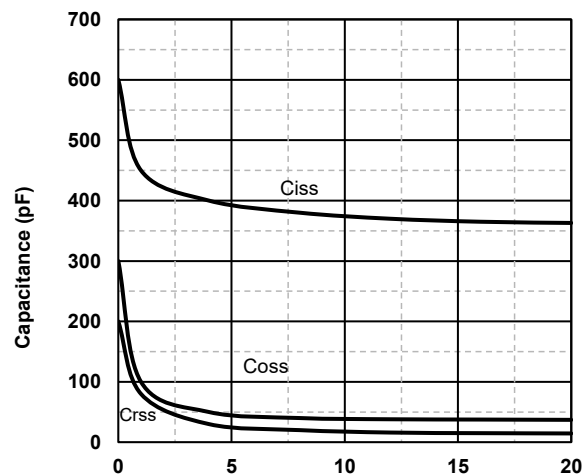
**T<sub>j</sub> - Junction Temperature (°C)**  
**Fig3. Normalized On-Resistance Vs. Temperature**



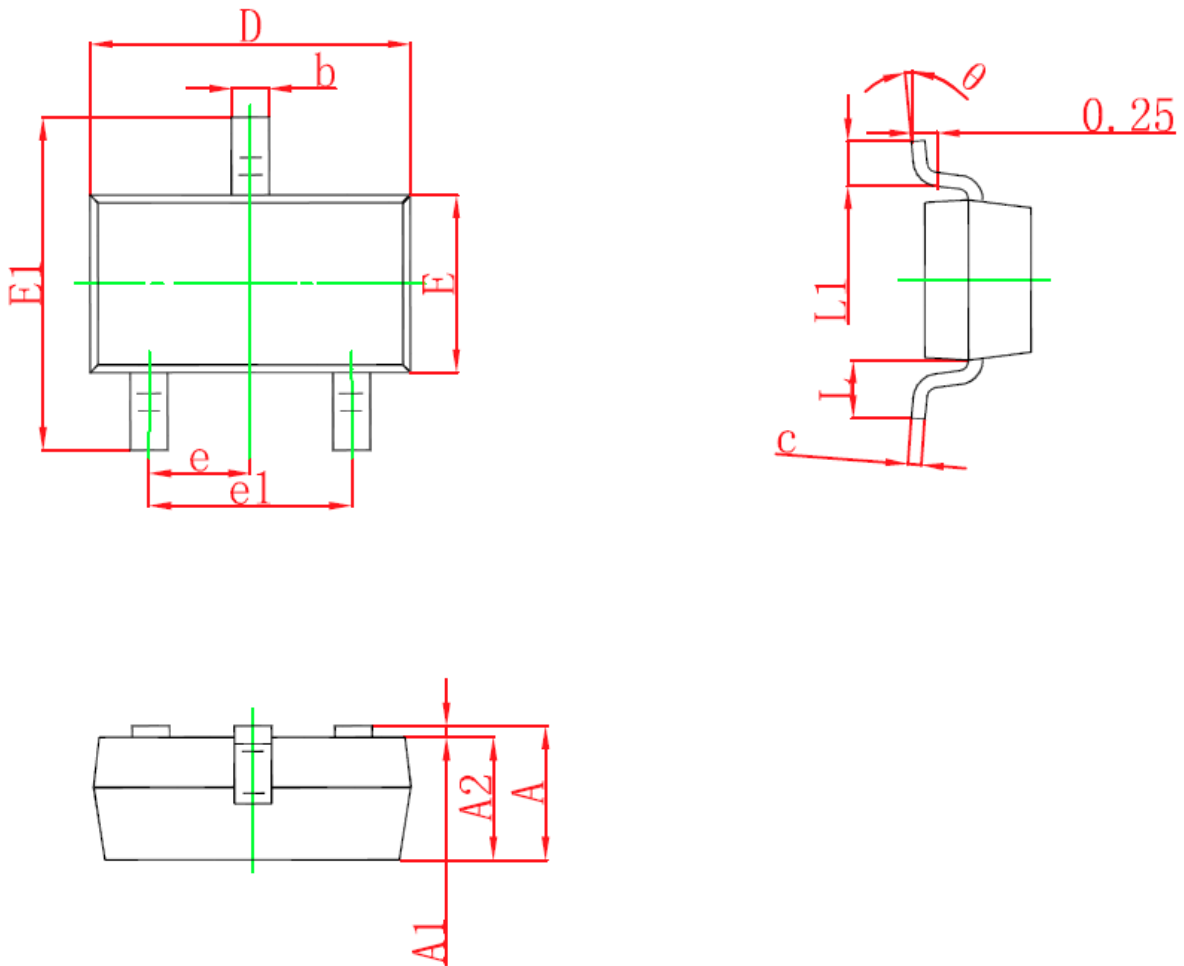
**I<sub>D</sub>, Drain-Source Current (A)**  
**Fig4. On-Resistance Vs. Drain-Source Current**



**V<sub>DS</sub>, Drain -Source Voltage (V)**  
**Fig5. Maximum Safe Operating Area**



**V<sub>DS</sub>, Drain-Source Voltage (V)**  
**Fig6 Typical Capacitance Vs. Drain-Source Voltage**

**SOT-23 Package information**


Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E1	2.250	2.550	0.088	0.100
E	1.200	1.400	0.047	0.055
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
$\theta$	0°	8°	0°	8°